

# FFPF10H60S Hyperfast 2 Rectifier

# April 2007

#### **Features**

- High Speed Switching (t<sub>rr</sub>=25ns(Typ.) @ I<sub>F</sub>=10A)
- High Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- Low Forward Voltage( V<sub>F</sub>=2.1V(Typ.) @ I<sub>F</sub>=10A )

# **Applications**

- General Purpose
- Switching Mode Power Supply
- · Free-wheeling diode for motor application
- · Power switching circuits

## 10A, 600V Hyperfast 2 Rectifier

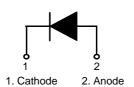
The FFPF10H60S is hyperfast2 rectifier ( $t_{rr}$ =25ns(Typ.) @  $I_F$ =10A). it has half the recovery time of ultrafast rectifier and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors

# **Pin Assignments**



1. Cathode 2. Anode



## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	600	V	
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V	
$V_R$	DC Blocking Voltage	600	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 85 °C	10	А	
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave		А	
$T_{J_i}T_{STG}$	Operating Junction and Storage Temperature	- 65 to +150	°C	

# Thermal Characteristics $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.4	°C/W

## **Package Marking and Ordering Information**

<b>Device Marking</b>	Device	Package	Reel Size	Tape Width	Quantity
F10H60S	FFPF10H60STU	TO-220F	=	=	50

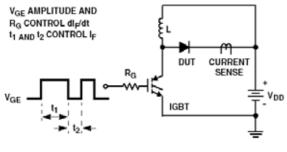
# Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Parameter	Conditions		Min.	Тур.	Max	Units
V <sub>FM</sub> <sup>1</sup>	I <sub>F</sub> = 10A I <sub>F</sub> = 10A	$T_C = 25 ^{\circ}C$ $T_C = 125 ^{\circ}C$	-	2.1 -	2.5 2.2	V V
I <sub>RM</sub> <sup>1</sup>	V <sub>R</sub> = 600V V <sub>R</sub> = 600V	$T_C = 25$ °C $T_C = 125$ °C	- -	- -	1 2	mA mA
t <sub>rr</sub>	$I_F$ =1A, di/dt = 100A/ $\mu$ s, V <sub>CC</sub> = 30V $I_F$ =10A, di/dt = 50A/ $\mu$ s, V <sub>CC</sub> = 390V $I_F$ =10A, di/dt = 200A/ $\mu$ s, V <sub>CC</sub> = 390V	$T_C = 25 ^{\circ}\text{C}$ $T_C = 25 ^{\circ}\text{C}$ $T_C = 25 ^{\circ}\text{C}$	- - -	- 25 21	35 40 -	ns ns ns
t <sub>a</sub> t <sub>b</sub> Q <sub>rr</sub>	$I_F = 10A$ , di/dt = 50A/ $\mu$ s, $V_{CC} = 390V$	$T_C = 25 ^{\circ}\text{C}$ $T_C = 25 ^{\circ}\text{C}$ $T_C = 25 ^{\circ}\text{C}$	- - -	15 10 9.0	- - -	ns ns nC
W <sub>AVL</sub>	Avalanche Energy (L = 40mH)		20	-	-	mJ

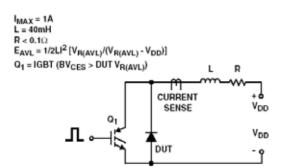
#### Notes:

1. Pulse : Test Pulse width =  $300\mu s$ , Duty Cycle = 2%

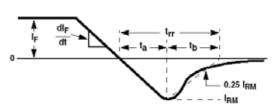
#### **Test Circuit and Waveforms**



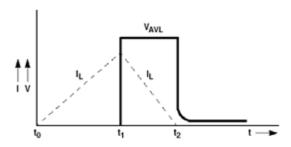




AVALANCHE ENERGY TEST CIRCUIT



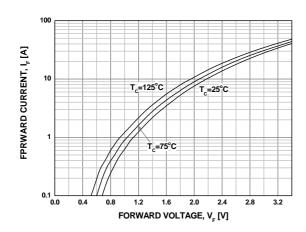
t<sub>rr</sub> WAVEFORMS AND DEFINITIONS



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

# Typical Performance Characteristics T<sub>C</sub> = 25°C unless otherwise noted

Figure 1. Typical Forward Voltage Drop



**Figure 2. Typical Reverse Current** 

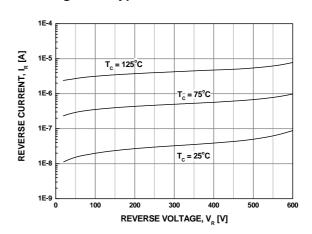


Figure 3. Typical Junction Capacitance

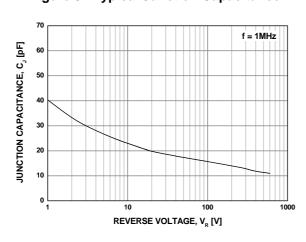


Figure 4. Typical Reverse Recovery Time

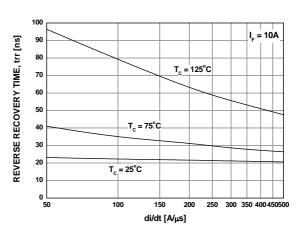
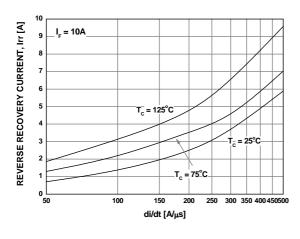
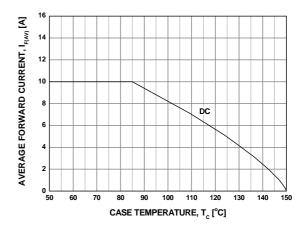


Figure 5. Typical Reverse Recovery Current

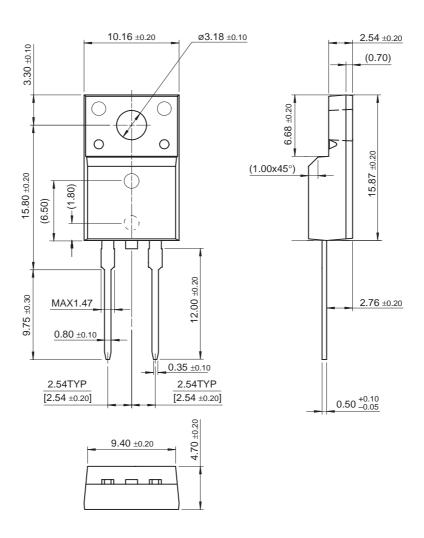


**Figure 6. Forward Current Deration Curve** 



## **Mechanical Dimensions**

# TO-220F 2L



Dimensions in Millimeters





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E <sup>2</sup> CMOS™	MSX™	RapidConnect™	TinyWire™
EcoSPARK <sup>®</sup>	MSXPro™	ScalarPump™	TruTranslation™
EnSigna™	OCXTM	SMART START™	µSerDes™
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FAST <sup>®</sup>	OPTOPLANAR <sup>®</sup>	SuperFET™	VCX <sup>TM</sup>
FASTr™	PACMAN™	SuperSOT™-3	Wire™
FPS™	POP™	SuperSOT™-6	
FRFET <sup>®</sup>	Power220 <sup>®</sup>	SuperSOT™-8	

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